

Data Sheet

March 8, 2007

专业PCB打样工厂

FN7278.2

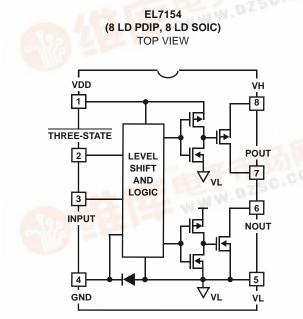
24小时加急出货**上7154** 

### High Speed, Monolithic Pin Driver

The EL7154 three-state pin driver is particularly well suited for ATE and level shifting applications. The 4A peak drive capability, makes the EL7154 an excellent choice when driving high speed capacitive lines.

The P-Channel MOSFET is completely isolated from the power supply, providing a high degree of flexibility. Pin (7) can be grounded, and the output can be taken from pin (8) when a "source follower" output is desired. The N-Channel MOSFET has an isolated drain, but shares a common bus with pre-drivers and level shifter circuits. This is necessary to ensure that the N-Channel device can turn off effectively when V<sub>1</sub> goes below GND. In some power-FET and IGBT applications, negative drive is desirable to insure effective turn-off. The EL7154 can be used in these applications by returning  $V_L$  to a moderate negative potential.

### Pinout



### Truth Table

df.dzsc.com

THREE-STATE	INPUT	Роит	NOUT
0	0	Open	Open
0	1	Open	Open
1	0	HIGH	Open
1	1	Open	LOW

Manufactored under U.S. Patent Nos. 5,334,883, #5,341,047, #5,352,578, #5,352,389, #5,351,012, #5,374,898

### Features

- Comparatively low cost
- Three-State output
- 3V and 5V Input compatible
- Clocking speeds up to 10MHz
- 20ns Switching/delay time •
- 4A Peak drive
- Isolated drains
- Low output impedance: 2.5Ω
- Low quiescent current: 5mA
- Wide operating voltage: 4.5V to16V
- Isolated P-Channel device
- Separate ground and V<sub>1</sub> pins
- Pb-free plus anneal available (RoHS compliant)

### Applications

- Loaded circuit board testers
- Digital testers
- WWW.DZSC.CO Level shifting below GND
- IGBT drivers
- CCD drivers



### Ordering Information

PART NUMBER	PART MARKING	TAPE AND REEL	PACKAGE	PKG. DWG. #	
EL7154CN	EL7154CN	-	8 Ld PDIP	MDP0031	
EL7154CNZ	EL7154CN Z	-	8 Ld PDIP* (Pb-free)	MDP0031	
EL7154CS	7154CS	-	8 Ld SOIC	MDP0027	
EL7154CS-T7	7154CS	7"	8 Ld SOIC	MDP0027	
EL7154CS-T13	7154CS	13"	8 Ld SOIC	MDP0027	
EL7154CSZ (See Note)	7154CSZ	-	8 Ld SOIC (Pb-free)	MDP0027	
EL7154CSZ-T7 (See Note)	7154CSZ	7"	8 Ld SOIC (Pb-free)	MDP0027	
EL7154CSZ-T13 (See Note)	7154CSZ	13"	8 Ld SOIC (Pb-free)	MDP0027	

\*Pb-free PDIPs can be used for through hole wave solder processing only. They are not intended for use in Reflow solder processing applications. NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

### Nominal Operating Voltage Range

PIN	MIN	MAX
VL	-3	0
$V_{DD}$ to $V_{L}$	5	15
$V_{H}$ to $V_{L}$	2	15
$V_{DD}$ to $V_{H}$	-0.5	15
V <sub>DD</sub>	5	15

Absolute Max	kimum Ratings	$(T_A = +25^{\circ}C)$
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Supply (V<sub>DD</sub> to V<sub>L</sub>; V<sub>H</sub> to V<sub>L</sub>, V<sub>H</sub> to GND),

V+ to V <sub>H</sub>
V <sub>L</sub> to GND5V
Input Pins
Peak Output Current

#### **Thermal Information**

Storage Temperature Range
Power Dissipation
SOIC
PDIP*1050mW
Pb-free reflow profilesee link below
http://www.intersil.com/pbfree/Pb-FreeReflow.asp
*Pb-free PDIPs can be used for through hole wave solder
processing only. They are not intended for use in Reflow solder processing applications

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore:  $T_J = T_C = T_A$ 

PARAMETER	DESCRIPTION	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
INPUT						4
VIH	Logic "1" Input Voltage		2.4			V
Ιн	Logic "1" Input Current	$V_{IH} = V_{DD}$		0.1	10	μA
V <sub>IL</sub>	Logic "0" Input Voltage				0.6	V
IIL	Logic "0" Input Current	$V_{IL} = 0V$		0.1	10	μA
V <sub>HVS</sub>	Input Hysteresis			0.3		V
OUTPUT		I				-
R <sub>OH</sub>	Pull-Up Resistance	I <sub>OUT</sub> = -100mA		1.5	4	Ω
R <sub>OL</sub>	Pull-Down Resistance	I <sub>OUT</sub> = +100mA		2	4	Ω
IOUT	Output Leakage Current	V <sub>DD</sub> /GND		0.2	10	μA
I <sub>PK</sub>	Peak Output Current	Source/Sink		4.0		А
IDC	Continuous Output Current	Source/Sink	200			mA
POWER SUPPLY				1		4
I <sub>S</sub>	Power Supply Current	Inputs = V <sub>DD</sub>		1	2.5	mA
V <sub>S</sub>	Operating Voltage		4.5		16	V
I <sub>G</sub>	Current to GND (Pin 4)			1	10	μA
lΗ	Off Leakage at V <sub>H</sub>	Pin 8 = 0V		1	10	μA

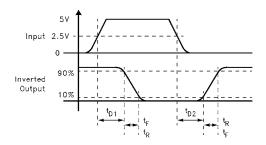
#### **DC Electrical Specifications** $T_A = +25^{\circ}C$ , $V_{DD} = +12V$ , $V_H = +12V$ , $V_L = -3V$ , unless otherwise specified.

### AC Electrical Specifications $T_A = +25^{\circ}C$ unless otherwise specified

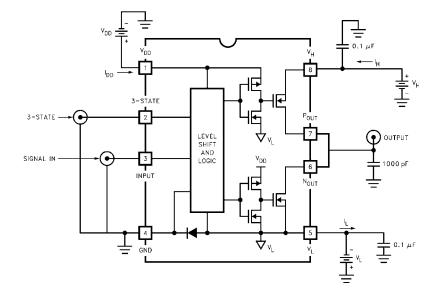
PARAMETER	DESCRIPTION	<b>TEST CONDITIONS</b>	MIN	TYP	MAX	UNITS
SWITCHING CHAR	ACTERISTICS ( $V_{DD} = V_{H} = 12V; V_{L} = -$	3V)				·
t <sub>R</sub>	Rise Time	C <sub>L</sub> = 100pF		4	25	ns
		C <sub>L</sub> = 2000pF		20		
t <sub>F</sub>	Fall Time	C <sub>L</sub> = 100pF		4	25	ns
		$C_{L} = 2000 pF$		20		
t <sub>D-1</sub>	Turn-Off Delay Time	C <sub>L</sub> = 2000pF		20	25	ns
t <sub>D-2</sub>	Turn-On Delay Time	$C_{L} = 2000 pF$		10	25	ns
t <sub>D-1</sub>	Three-State Delay				25	ns
t <sub>D-2</sub>	Three-State Delay				25	ns

### EL7154

# Timing Table



# Standard Test Configuration



**Typical Performance Curves** 

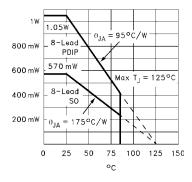


FIGURE 1. MAX POWER DERATING CURVES

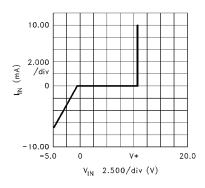


FIGURE 3. INPUT CURRENT vs VOLTAGE

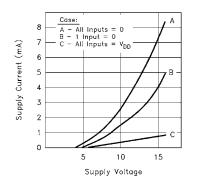


FIGURE 5. QUIESCENT SUPPLY CURRENT

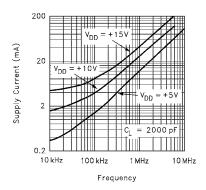


FIGURE 7. AVERAGE SUPPLY CURRENT vs VOLTAGE AND FREQUENCY

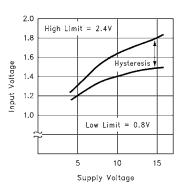


FIGURE 2. SWITCH THRESHOLD vs SUPPLY VOLTAGE

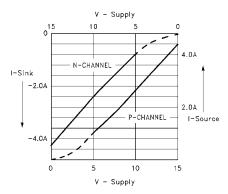


FIGURE 4. PEAK DRIVE vs SUPPLY VOLTAGE

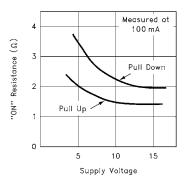
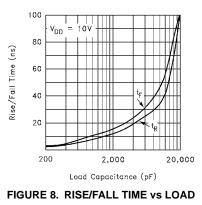
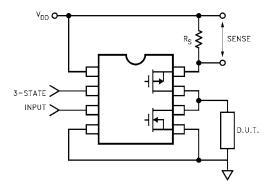


FIGURE 6. "ON" RESISTANCE vs SUPPLY VOLTAGE



## **Typical Applications**





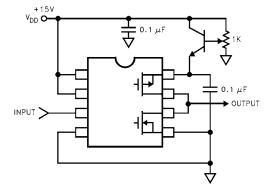


FIGURE 10. ADJUSTABLE AMPLITUDE PULSE GENERATOR

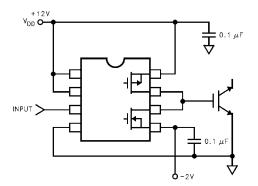


FIGURE 11. IGBT DRIVER WITH NEGATIVE SWING

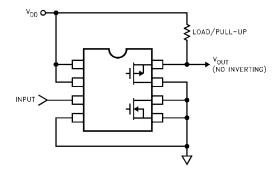


FIGURE 12. PMDS FOLLOWER

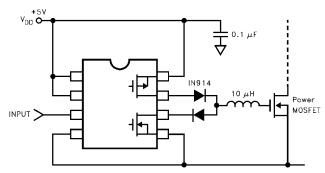
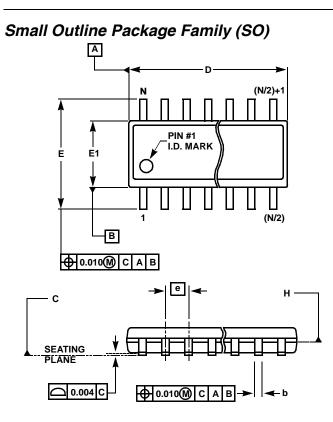
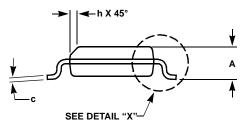
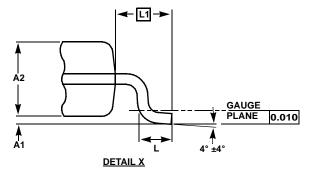


FIGURE 13. RESONANT GATE DRIVER







#### MDP0027

#### SMALL OUTLINE PACKAGE FAMILY (SO)

NOTES	TOLERANCE	INCHES							
		SO28 (SOL-28)	SO24 (SOL-24)	SO20 (SOL-20)	SO16 (0.300") (SOL-16)	SO16 (0.150")	SO-14	SO-8	SYMBOL
-	MAX	0.104	0.104	0.104	0.104	0.068	0.068	0.068	А
-	±0.003	0.007	0.007	0.007	0.007	0.006	0.006	0.006	A1
-	±0.002	0.092	0.092	0.092	0.092	0.057	0.057	0.057	A2
-	±0.003	0.017	0.017	0.017	0.017	0.017	0.017	0.017	b
-	±0.001	0.011	0.011	0.011	0.011	0.009	0.009	0.009	С
1, 3	±0.004	0.704	0.606	0.504	0.406	0.390	0.341	0.193	D
-	±0.008	0.406	0.406	0.406	0.406	0.236	0.236	0.236	Е
2, 3	±0.004	0.295	0.295	0.295	0.295	0.154	0.154	0.154	E1
-	Basic	0.050	0.050	0.050	0.050	0.050	0.050	0.050	е
-	±0.009	0.030	0.030	0.030	0.030	0.025	0.025	0.025	L
-	Basic	0.056	0.056	0.056	0.056	0.041	0.041	0.041	L1
-	Reference	0.020	0.020	0.020	0.020	0.013	0.013	0.013	h
-	Reference	28	24	20	16	16	14	8	Ν

NOTES:

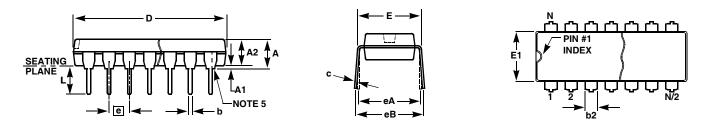
1. Plastic or metal protrusions of 0.006" maximum per side are not included.

2. Plastic interlead protrusions of 0.010" maximum per side are not included.

3. Dimensions "D" and "E1" are measured at Datum Plane "H".

4. Dimensioning and tolerancing per ASME Y14.5M-1994

### Plastic Dual-In-Line Packages (PDIP)



#### MDP0031

### PLASTIC DUAL-IN-LINE PACKAGE

	INCHES						
SYMBOL	PDIP8	PDIP14	PDIP16	PDIP18	PDIP20	TOLERANCE	NOTES
A	0.210	0.210	0.210	0.210	0.210	MAX	
A1	0.015	0.015	0.015	0.015	0.015	MIN	
A2	0.130	0.130	0.130	0.130	0.130	±0.005	
b	0.018	0.018	0.018	0.018	0.018	±0.002	
b2	0.060	0.060	0.060	0.060	0.060	+0.010/-0.015	
с	0.010	0.010	0.010	0.010	0.010	+0.004/-0.002	
D	0.375	0.750	0.750	0.890	1.020	±0.010	1
E	0.310	0.310	0.310	0.310	0.310	+0.015/-0.010	
E1	0.250	0.250	0.250	0.250	0.250	±0.005	2
е	0.100	0.100	0.100	0.100	0.100	Basic	
eA	0.300	0.300	0.300	0.300	0.300	Basic	
eB	0.345	0.345	0.345	0.345	0.345	±0.025	
L	0.125	0.125	0.125	0.125	0.125	±0.010	
N	8	14	16	18	20	Reference	

#### NOTES:

1. Plastic or metal protrusions of 0.010" maximum per side are not included.

2. Plastic interlead protrusions of 0.010" maximum per side are not included.

3. Dimensions E and eA are measured with the leads constrained perpendicular to the seating plane.

4. Dimension eB is measured with the lead tips unconstrained.

5. 8 and 16 lead packages have half end-leads as shown.

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